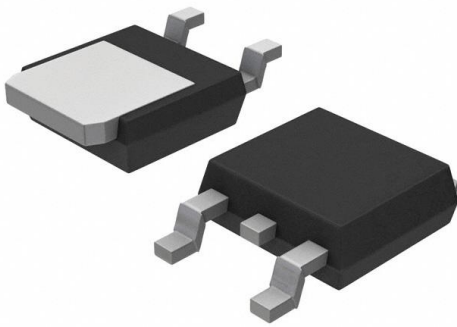


# SFT1345-TL-H Datasheet

[www.digi-electronics.com](http://www.digi-electronics.com)



<https://www.DiGi-Electronics.com>

DiGi Electronics Part Number	SFT1345-TL-H-DG
Manufacturer	<a href="#">onsemi</a>
Manufacturer Product Number	SFT1345-TL-H
Description	MOSFET P-CH 100V 11A TP-FA
Detailed Description	P-Channel 100 V 11A (Ta) 1W (Ta), 35W (Tc) Surface Mount TP-FA



Tel: +00 852-30501935

RFQ Email: [Info@DiGi-Electronics.com](mailto:Info@DiGi-Electronics.com)

DiGi is a global authorized distributor of electronic components.

## Purchase and inquiry

Manufacturer Product Number:

SFT1345-TL-H

Series:

-

FET Type:

P-Channel

Drain to Source Voltage (Vdss):

100 V

Drive Voltage (Max Rds On, Min Rds On):

4V, 10V

Vgs(th) (Max) @ Id:

-

Vgs (Max):

±20V

FET Feature:

-

Operating Temperature:

150°C (TJ)

Supplier Device Package:

TP-FA

Base Product Number:

SFT1345

Manufacturer:

onsemi

Product Status:

Obsolete

Technology:

MOSFET (Metal Oxide)

Current - Continuous Drain (Id) @ 25°C:

11A (Ta)

Rds On (Max) @ Id, Vgs:

275mOhm @ 5.5A, 10V

Gate Charge (Qg) (Max) @ Vgs:

21 nC @ 10 V

Input Capacitance (Ciss) (Max) @ Vds:

1020 pF @ 20 V

Power Dissipation (Max):

1W (Ta), 35W (Tc)

Mounting Type:

Surface Mount

Package / Case:

TO-252-3, DPAK (2 Leads + Tab), SC-63

## Environmental & Export classification

RoHS Status:

ROHS3 Compliant

REACH Status:

REACH Unaffected

HTSUS:

8541.29.0095

Moisture Sensitivity Level (MSL):

1 (Unlimited)

ECCN:

EAR99

# SFT1345

## Power MOSFET –100V, 275mΩ, –11A, Single P-Channel

This P-Channel Power MOSFET is produced using ON Semiconductor's trench technology, which is specifically designed to minimize gate charge and low on resistance. This device is suitable for applications with low gate charge driving or low on resistance requirements.

### Features

- Low On-Resistance
- 4V drive
- 100% Avalanche Tested
- ESD Diode-Protected Gate
- Pb-Free, Halogen Free and RoHS compliance

### Typical Applications

- Reverse Battery Protection
- Load Switch

### SPECIFICATIONS

#### ABSOLUTE MAXIMUM RATING at Ta = 25°C (Note 1, 2)

Parameter	Symbol	Value	Unit
Drain to Source Voltage	V <sub>DSS</sub>	–100	V
Gate to Source Voltage	V <sub>GSS</sub>	±20	V
Drain Current (DC)	I <sub>D</sub>	–11	A
Drain Current PW ≤ 10μs, duty cycle ≤ 1%	I <sub>DP</sub>	–44	A
Power Dissipation	P <sub>D</sub>	1.0	W
		T <sub>c</sub> =25°C	35
Junction Temperature	T <sub>j</sub>	150	°C
Storage Temperature	T <sub>stg</sub>	–55 to +150	°C

Note 1 : Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

### THERMAL RESISTANCE RATINGS

Parameter	Symbol	Value	Unit
Junction to Case Steady State	R <sub>θJC</sub>	3.57	°C/W
Junction to Ambient (Note 2)	R <sub>θJA</sub>	125	

Note 2 : Insertion mounted

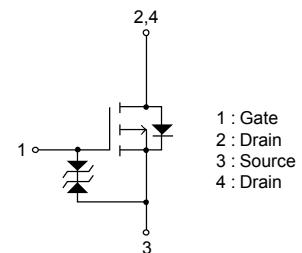


**ON Semiconductor®**

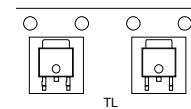
www.onsemi.com

V <sub>DSS</sub>	R <sub>DSON</sub> Max	I <sub>D</sub> Max
–100V	275mΩ@ –10V	–11A
	315mΩ@ –4.5V	
	330mΩ@ –4V	

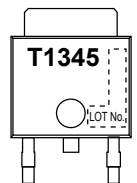
### ELECTRICAL CONNECTION P-Channel



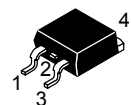
### PACKING TYPE : TL



### MARKING



IPAK(TP)



DPAK(TP-FA)

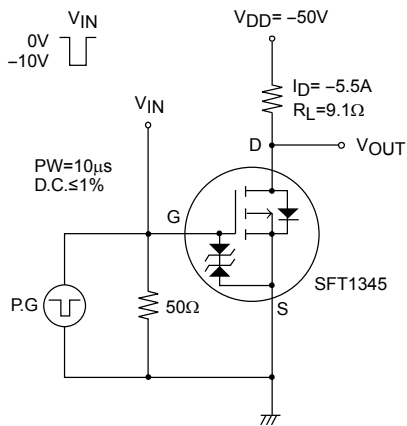
### ORDERING INFORMATION

See detailed ordering and shipping information on page 6 of this data sheet.

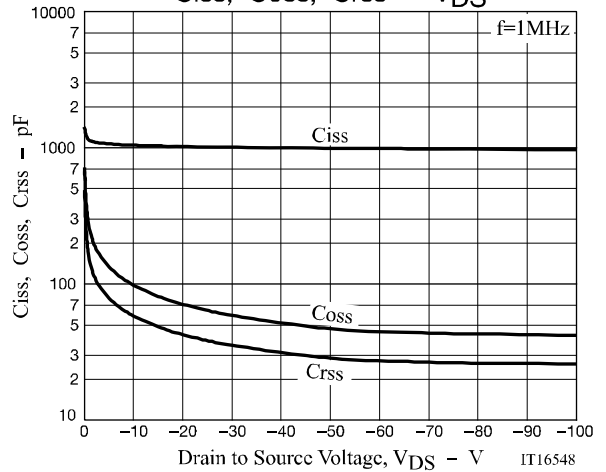
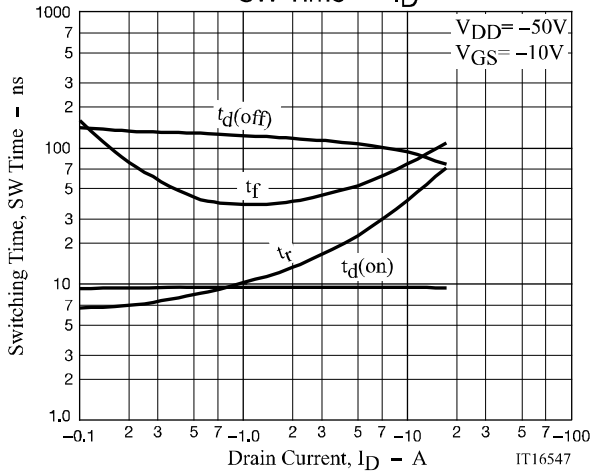
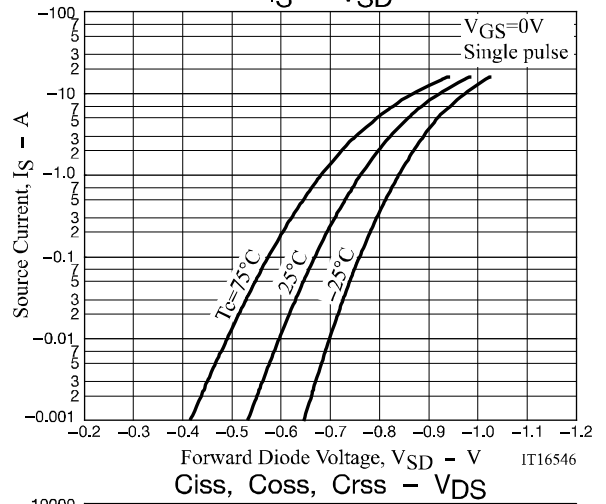
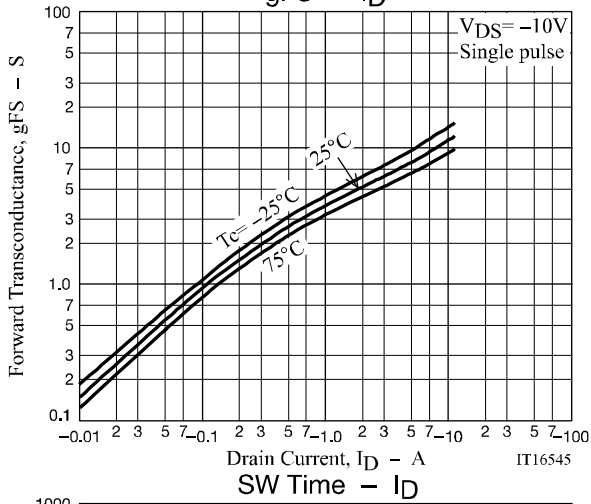
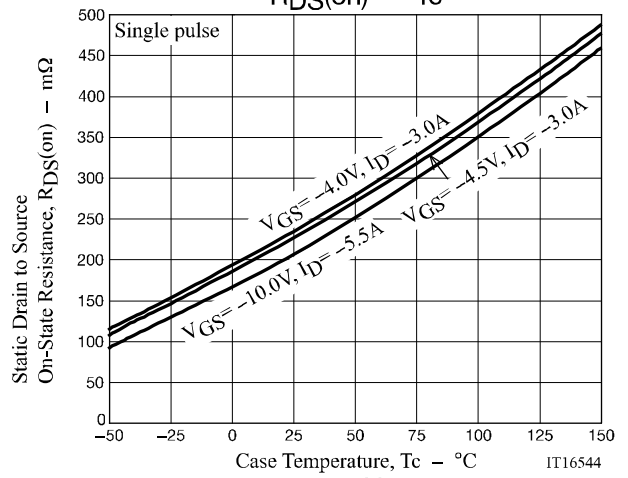
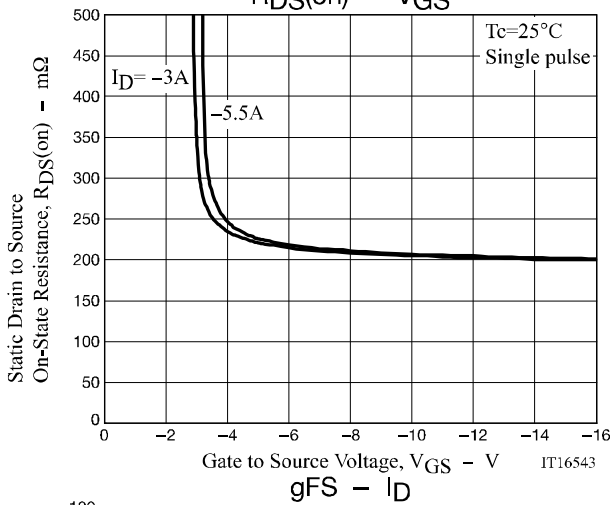
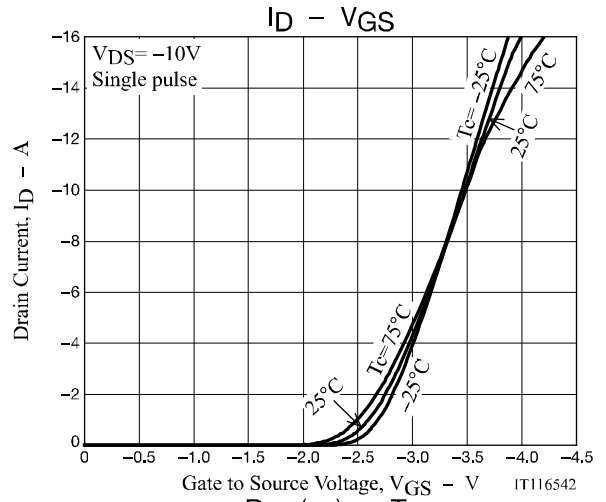
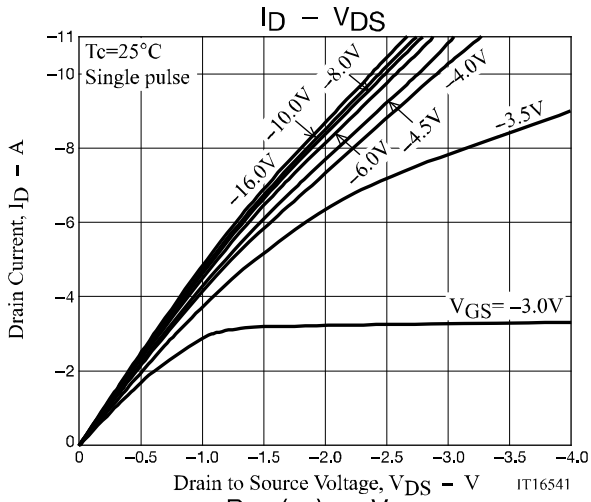
**SFT1345****ELECTRICAL CHARACTERISTICS** at  $T_a = 25^\circ\text{C}$  (Note 3)

Parameter	Symbol	Conditions	Value			Unit
			min	typ	max	
Drain to Source Breakdown Voltage	$V_{(BR)DSS}$	$I_D = -1\text{mA}$ , $V_{GS} = 0\text{V}$	-100			V
Zero-Gate Voltage Drain Current	$I_{DSS}$	$V_{DS} = -100\text{V}$ , $V_{GS} = 0\text{V}$			-1	$\mu\text{A}$
Gate to Source Leakage Current	$I_{GSS}$	$V_{GS} = \pm 16\text{V}$ , $V_{DS} = 0\text{V}$			$\pm 10$	$\mu\text{A}$
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = -10\text{V}$ , $I_D = -1\text{mA}$	-1.2		-2.6	V
Forward Transconductance	$g_{FS}$	$V_{DS} = -10\text{V}$ , $I_D = -5.5\text{A}$		8.5		S
Static Drain to Source On-State Resistance	$R_{DS(on)1}$	$I_D = -5.5\text{A}$ , $V_{GS} = -10\text{V}$		210	275	$\text{m}\Omega$
	$R_{DS(on)2}$	$I_D = -3\text{A}$ , $V_{GS} = -4.5\text{V}$		225	315	$\text{m}\Omega$
	$R_{DS(on)3}$	$I_D = -3\text{A}$ , $V_{GS} = -4\text{V}$		235	330	$\text{m}\Omega$
Input Capacitance	$C_{iss}$	$V_{DS} = -20\text{V}$ , $f = 1\text{MHz}$		1020		pF
Output Capacitance	$C_{oss}$			72		pF
Reverse Transfer Capacitance	$C_{rss}$			43		pF
Turn-ON Delay Time	$t_{d(on)}$		See specified Test Circuit		9.5	
Rise Time	$t_r$			25		ns
Turn-OFF Delay Time	$t_{d(off)}$			105		ns
Fall Time	$t_f$			55		ns
Total Gate Charge	$Q_g$	$V_{DS} = -50\text{V}$ , $V_{GS} = -10\text{V}$ , $I_D = -11\text{A}$			21	
Gate to Source Charge	$Q_{gs}$			3.6		nC
Gate to Drain "Miller" Charge	$Q_{gd}$			4.5		nC
Forward Diode Voltage	$V_{SD}$	$I_S = -11\text{A}$ , $V_{GS} = 0\text{V}$		-0.93	-1.5	V

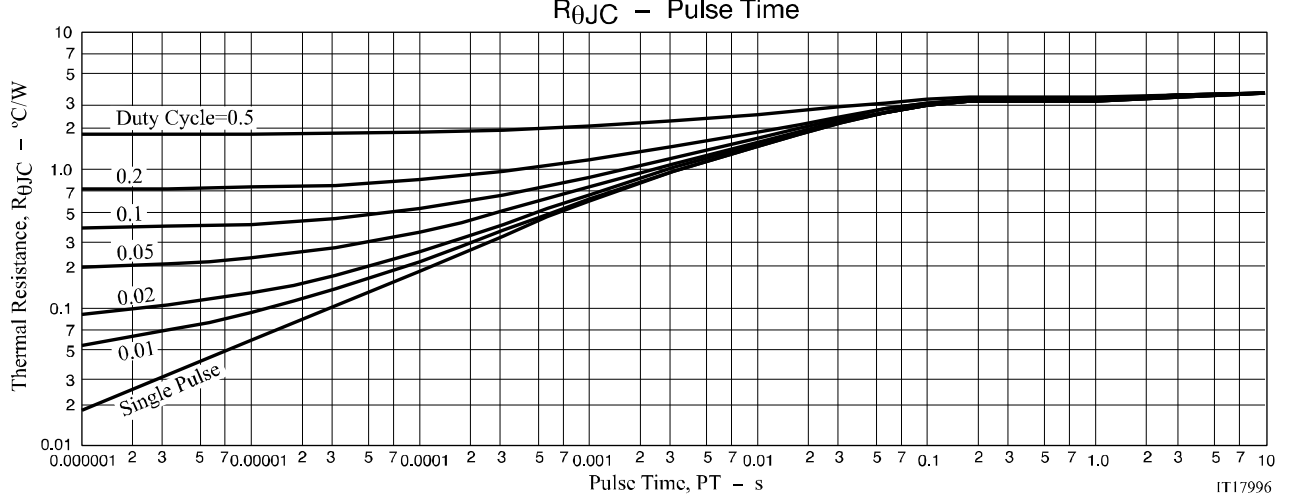
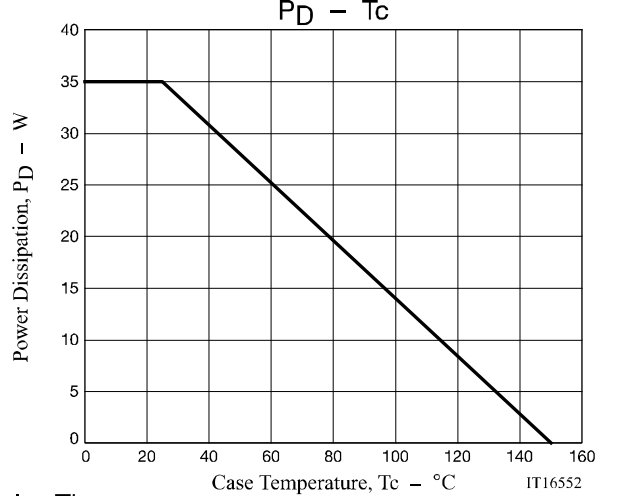
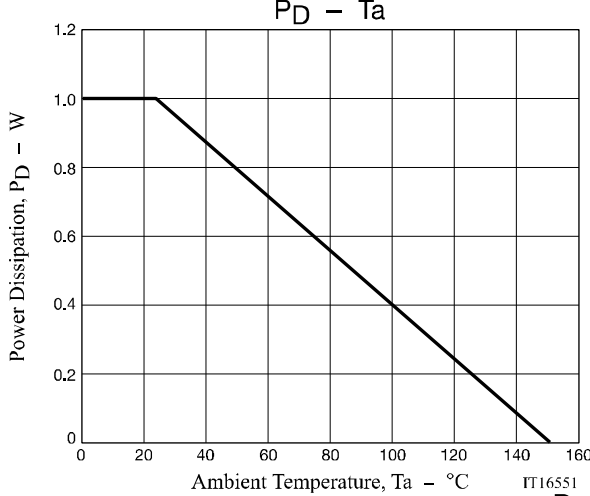
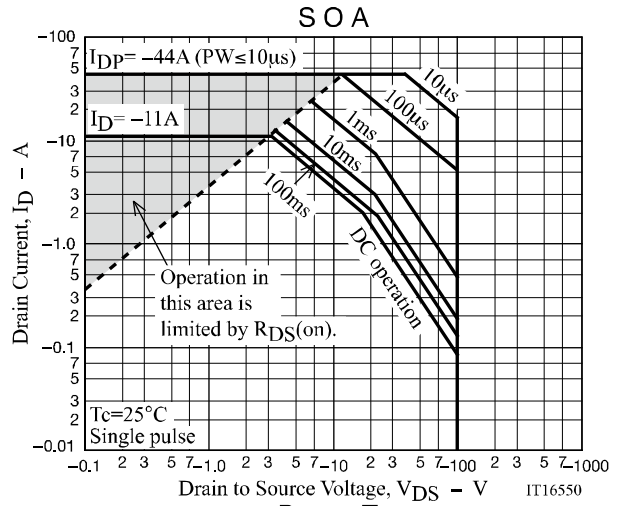
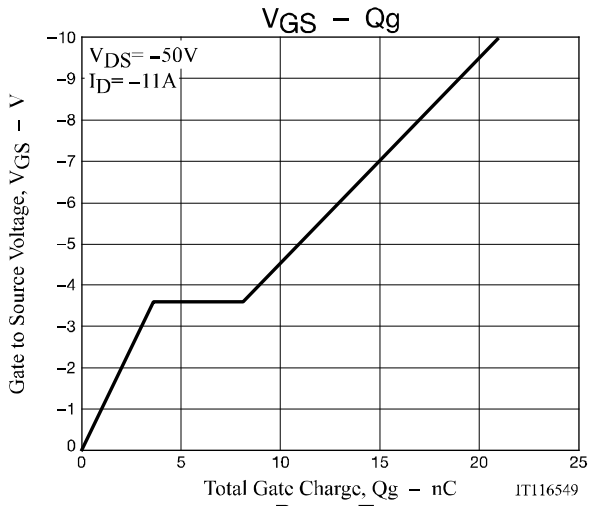
Note 3 : Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

**Switching Time Test Circuit**

**SFT1345**



### SFT1345

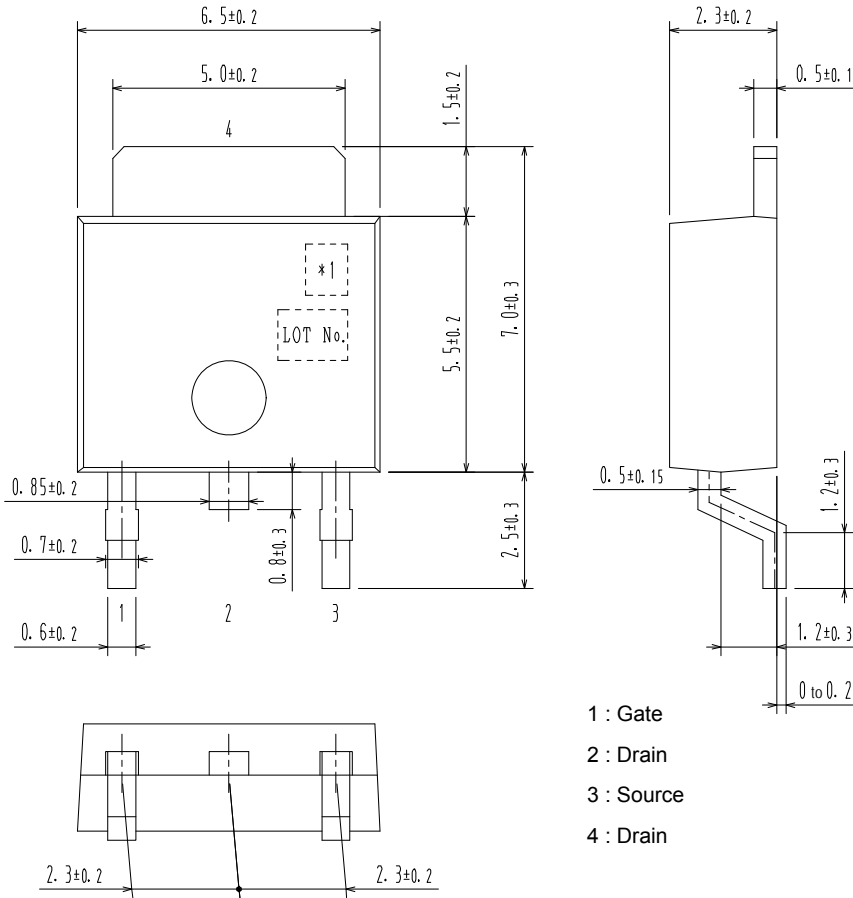


# SFT1345

## PACKAGE DIMENSIONS

unit : mm

DPAK / TP-FA  
CASE 369AH  
ISSUE 0

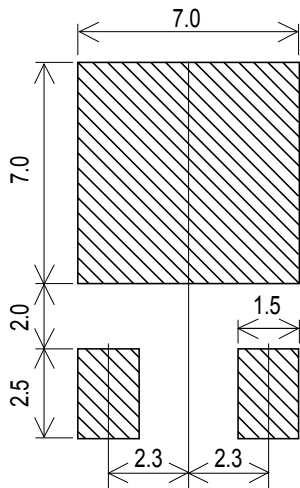


- 1 : Gate
- 2 : Drain
- 3 : Source
- 4 : Drain

Pin 2 is idle pin with electrical designation only carried.

\*1: Lot indication

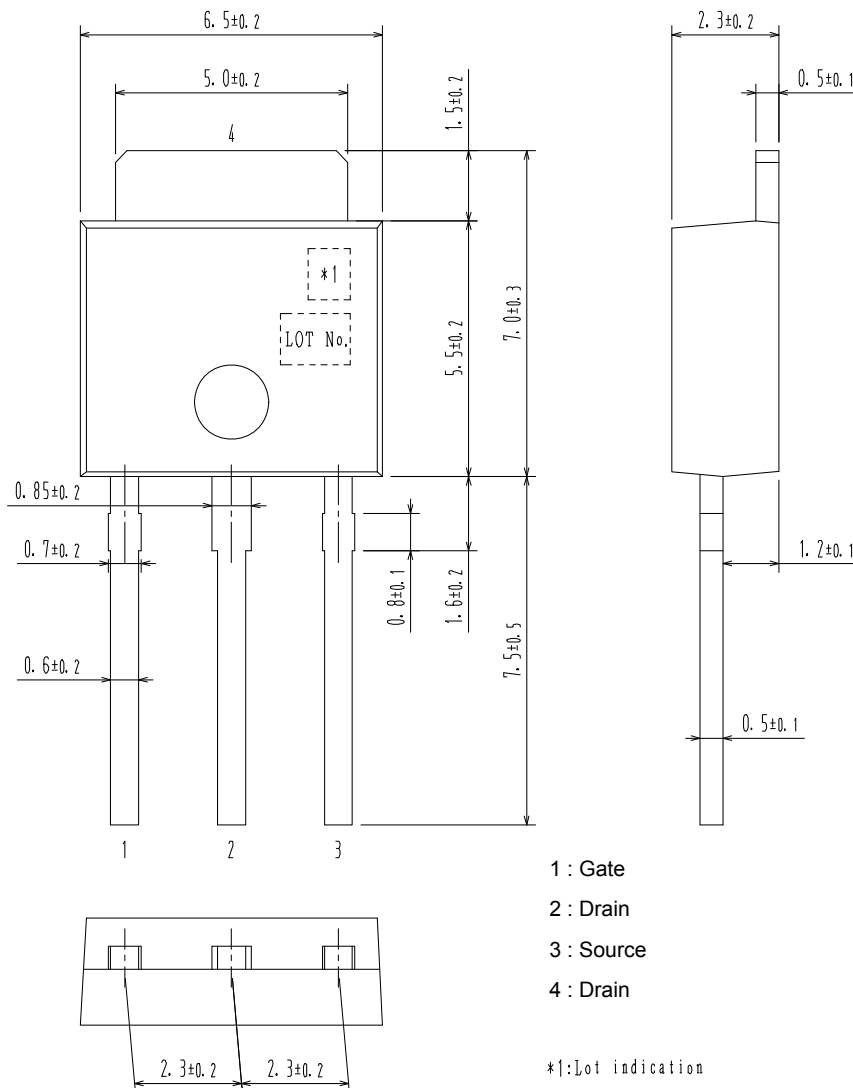
## Recommended Soldering Footprint



## SFT1345

## PACKAGE DIMENSIONS

unit : mm

IPAK / TP  
CASE 369AJ  
ISSUE O

## ORDERING INFORMATION

Device	Marking	Package	Shipping (Qty / Packing)
SFT1345-H	T1345	IPAK / TP (Pb-Free / Halogen Free)	500 / Bag
SFT1345-TL-H	T1345	DPAK / TP-FA (Pb-Free / Halogen Free)	700 / Tape & Reel

† For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D. [http://www.onsemi.com/pub\\_link/Collateral/BRD8011-D.PDF](http://www.onsemi.com/pub_link/Collateral/BRD8011-D.PDF)

Note on usage : Since the SFT1345 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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